



GaAs MMIC I/Q MIXER MODULE 6 - 10 GHz

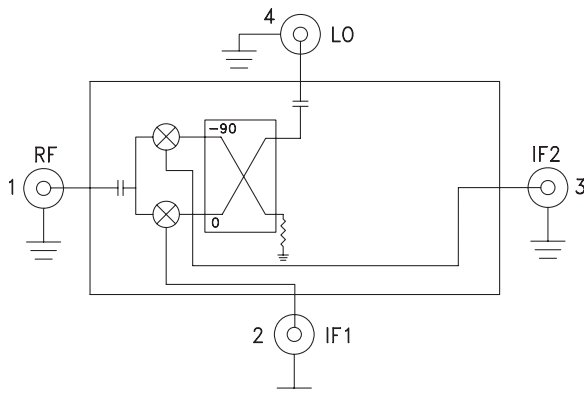


Typical Applications

The HMC-C041 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military End-Use

Functional Diagram



Features

- Wide IF Bandwidth: DC - 3.5 GHz
- Image Rejection: 35 dB
- LO to RF Isolation: 45 dB
- High Input IP3: +25 dBm
- Hermetically Sealed Module
- Field Replaceable SMA Connectors
- 55 to +85 °C Operating Temperature

General Description

The HMC-C041 is a passive I/Q MMIC mixer housed in a miniature hermetic module which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The module utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated on a GaAs MESFET process. A low frequency quadrature hybrid was used to produce a 100 MHz USB IF output. This MMIC based module is a more reliable and consistent alternative to hybrid style I/Q Mixers and Single Sideband Converter assemblies. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $IF = 100\text{ MHz}$, $LO = +19\text{ dBm}^*$

Parameter	Min.	Typ.	Max.	Units
Frequency Range, RF/LO		6 - 10		GHz
Frequency Range, IF		DC - 3.5		GHz
Conversion Loss (As IRM)		7.5	10	dB
Image Rejection	20	35		dB
1 dB Compression (Input)		+17		dBm
LO to RF Isolation	35	45		dB
LO to IF Isolation	20	25		dB
IP3 (Input)		+25		dBm
Amplitude Balance		0.5		dB
Phase Balance		5		Deg

* Unless otherwise noted, all measurements performed as downconverter.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order Online at www.hittite.com



GaAs MMIC I/Q MIXER MODULE
6 - 10 GHz

Data taken As IRM With External IF Hybrid
Conversion Gain vs. Temperature

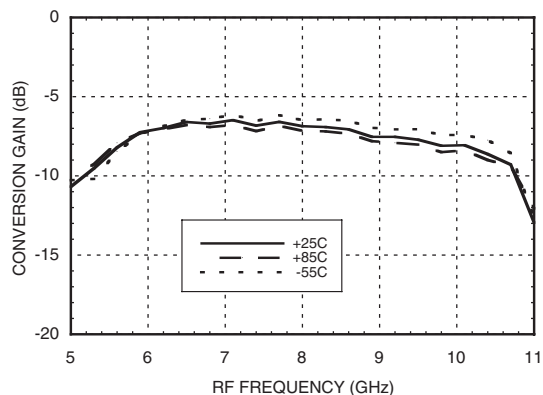
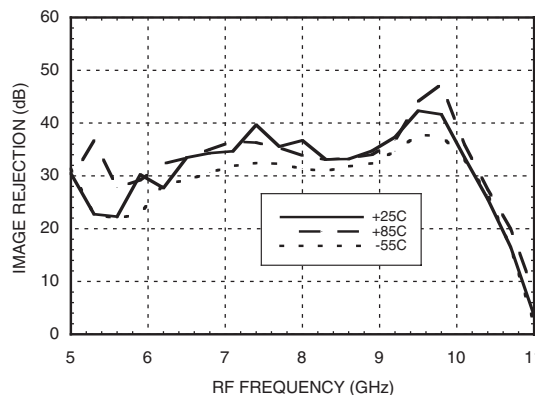
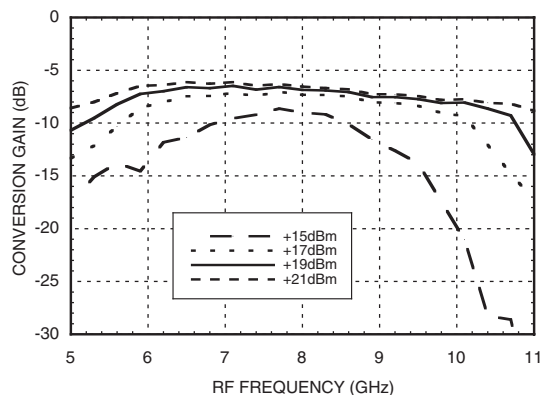


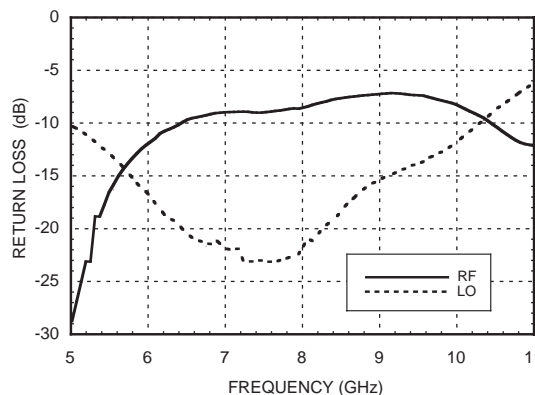
Image Rejection vs. Temperature



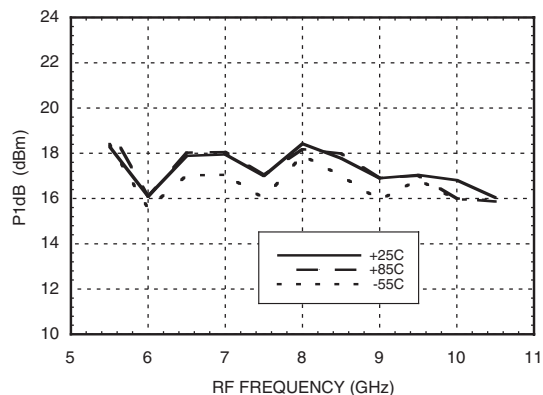
Conversion Gain vs. LO Drive



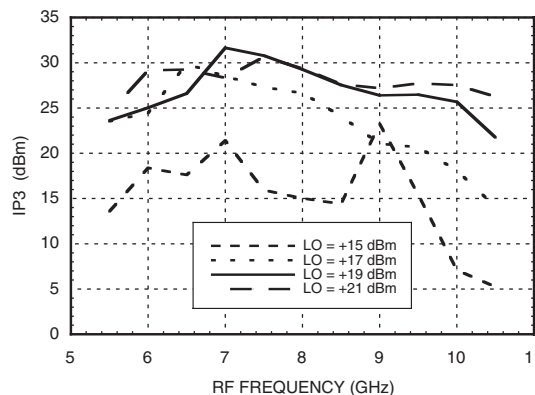
Return Loss



Input P1dB vs. Temperature



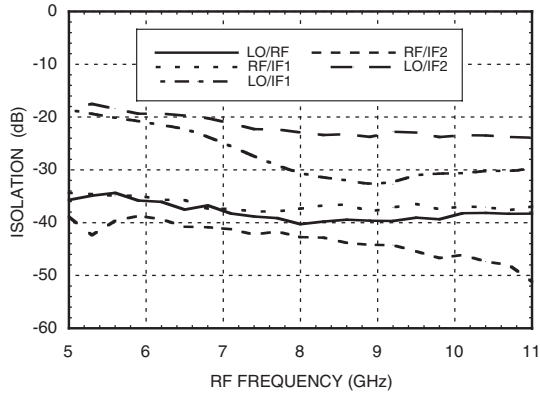
Input IP3 vs. LO Drive



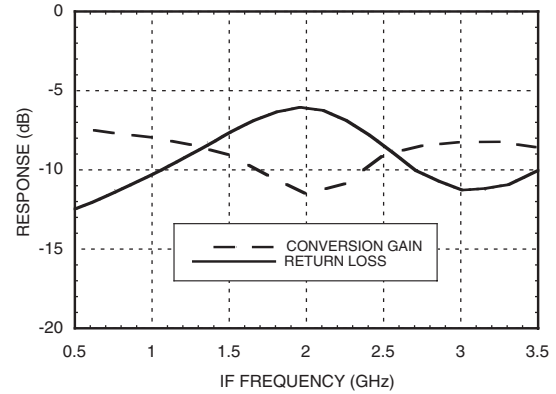


Quadrature Channel Data Taken Without IF Hybrid

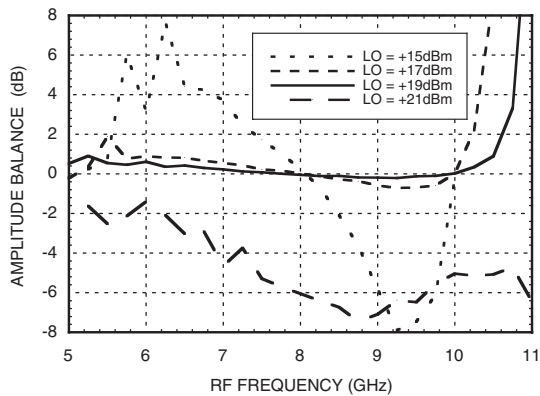
Isolations



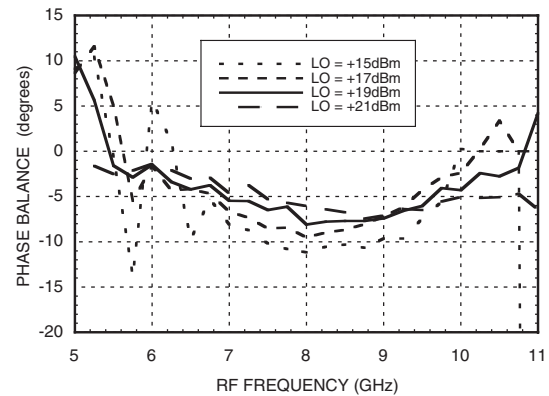
IF Bandwidth*



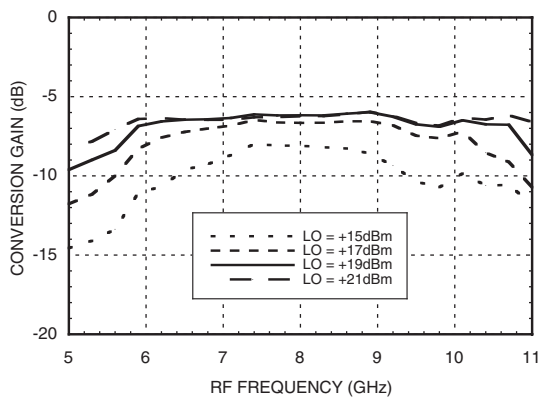
Amplitude Balance vs. LO Drive



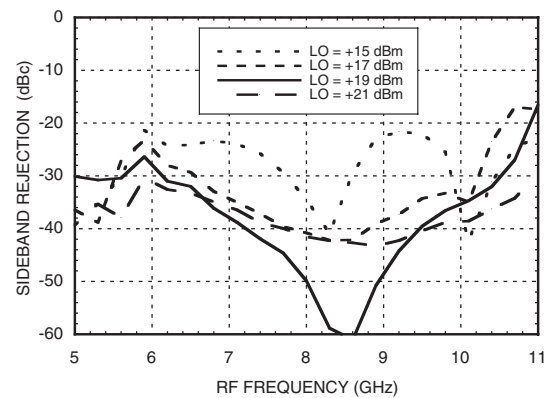
Phase Balance vs. LO Drive



Upconverter Performance Conversion Gain vs. LO Drive*



Upconverter Performance Sideband Rejection vs. LO Drive*



* Conversion gain data taken with external IF hybrid


Harmonics of LO

LO Freq. (GHz)	nLO Spur at RF Port			
	1	2	3	4
3.5	39	40	52	51
6.5	43	49	51	70
7.5	51	65	53	62
8.5	56	61	56	50
9.5	47	57	65	63
10.5	45	55	59	46

LO = +19 dBm
Values in dBc below input LO level measured at RF Port.

MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	xx	10	29	18	51
1	33	0	46	77	68
2	99	71	75	70	99
3	97	101	100	86	101
4	99	98	98	102	107

RF = 7.6 GHz @ -10 dBm
LO = 7.5 GHz @ +19 dBm
Data taken without IF hybrid
All values in dBc below IF power level

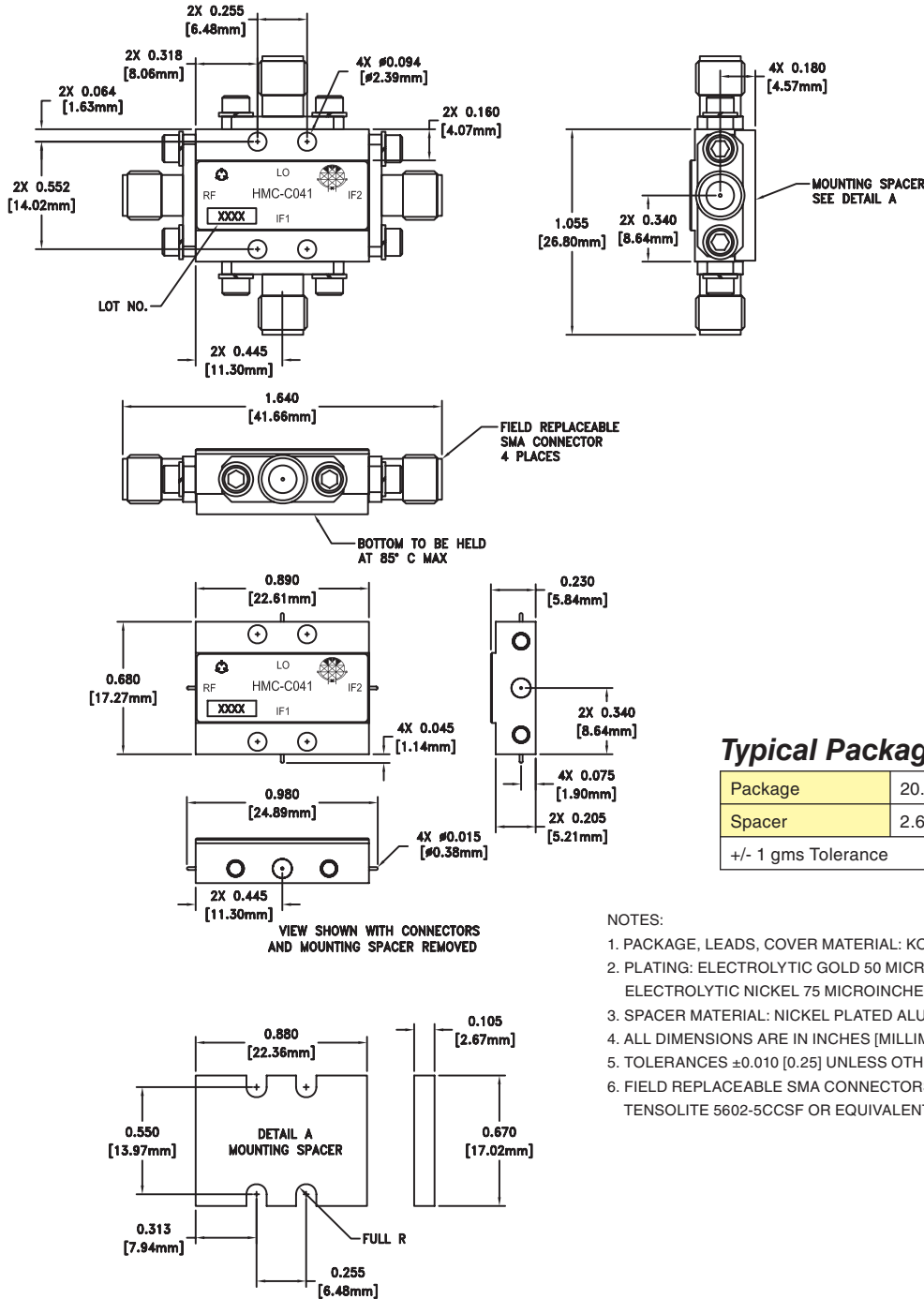
Absolute Maximum Ratings

RF / IF Input	+20 dBm
LO Drive	+27 dBm
Channel Temperature	150°C
Continuous Pdiss (T=85°C) (derate 7.8 mW/°C above 85°C)	507 mW
Thermal Resistance (R _{TH}) (junction to die bottom)	128 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Typical Package Weight


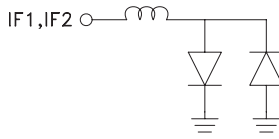
Package	20.0 gms
Spacer	2.6 gms
+/- 1 gms Tolerance	

NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
2. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
3. SPACER MATERIAL: NICKEL PLATED ALUMINUM
4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES ±0.010 [0.25] UNLESS OTHERWISE SPECIFIED.
6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602-5CCSF OR EQUIVALENT.



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RF	This pin is AC coupled and matched to 50 Ohms from 6 to 10 GHz.	RF 
2	IF1	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source/sink more than 3mA of current or part non-function and possible part failure will result.	IF1,IF2 
3	IF2		
4	LO	This pin is AC coupled and matched to 50 Ohms from 6 to 10 GHz.	LO 